

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION



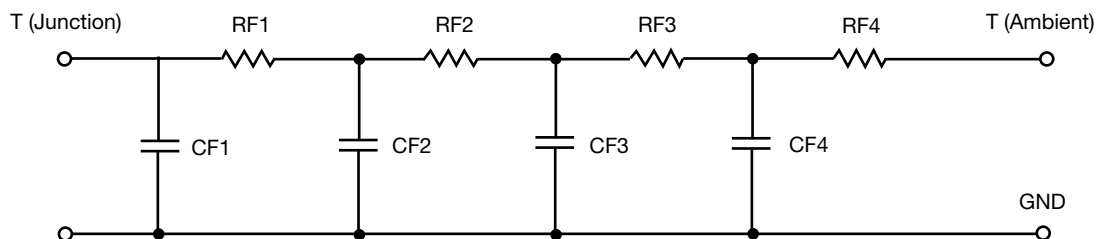
R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	60.5879	N/A	9.0645
RT2	16.9111	N/A	2.7530
RT3	61.1822	N/A	7.5907
RT4	25.8081	N/A	30.5803
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.4472	N/A	4.1332m
CT2	268.9344m	N/A	279.0965u
CT3	6.2219m	N/A	235.1040m
CT4	1.1320m	N/A	12.4045m

#### Note

N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION**



<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
<b>THERMAL RESISTANCE (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RF1	13.2458	N/A	4.5776
RF2	47.7806	N/A	19.6175
RF3	39.0015	N/A	23.0199
RF4	63.8436	N/A	3.2768
<b>THERMAL CAPACITANCE (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CF1	462.9800u	N/A	419.1650u
CF2	2.0270m	N/A	3.7791m
CF3	15.7875m	N/A	15.7277m
CF4	1.1631	N/A	1.0611

**Note**

N/A indicates not applicable

